



Docket No.: 60188-407

PATENT

2812
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Re Application of

ISHIBASHI, AKIHIKO, et al.

Serial No.: 09/692,211

Filed: October 20, 2000

For: METHOD OF FABRICATING NITRIDE SEMICONDUCTOR DEVICE

: Customer Number: 20277
:
: Confirmation Number: 6705
:
: Group Art Unit: 2812
:
: Examiner: Savitri MULPURI
:

Mail Stop
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Transmitted herewith is an Amendment in the above-identified application.

- ☐ No additional fee is required.
☐ Applicant is entitled to small entity status under 37 CFR 1.27
☒ Also attached: Declaration Under 37 CFR § 1.131, Petition for Extension of Time and Draft Japanese Patent Application

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	8	20	0	\$18.00 =	\$0.00
Independent Claims	2	3	0	\$84.00 =	\$0.00
Multiple claims newly presented					\$0.00
Fee for extension of time					\$410.00
					\$0.00
Total of Above Calculations					\$410.00

- ☒ Please charge my Deposit Account No. 500417 in the amount of \$410.00. An additional copy of this transmittal sheet is submitted herewith.
- ☒ The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 500417, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

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Date: September 8, 2003

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